

## Electronic Patent Application Fee Transmittal

<b>Application Number:</b>	10814482			
<b>Filing Date:</b>	31-Mar-2004			
<b>Title of Invention:</b>	Method for fabricating strained silicon-on-insulator structures and strained silicon-on insulator structures formed thereby			
First Named Inventor/Applicant Name:	Toshiharu Furukawa			
<b>Filer:</b>	William R. Allen/Angela Malik			
<b>Attorney Docket Number:</b>	ROC920030399US1			
Filed as Large Entity				
<b>Utility      Filing Fees</b>				
<b>Description</b>	<b>Fee Code</b>	<b>Quantity</b>	<b>Amount</b>	<b>Sub-Total in USD(\$)</b>
<b>Basic Filing:</b>				
<b>Pages:</b>				
<b>Claims:</b>				
<b>Miscellaneous-Filing:</b>				
<b>Petition:</b>				
<b>Patent-Appeals-and-Interference:</b>				
Filing a brief in support of an appeal	1402	1	500	500
Post-Allowance-and-Post-Issuance:				
<b>Extension-of-Time:</b>				



Description	Fee Code	Quantity	Amount	Sub-Total in USD(\$)
Miscellaneous:				
Total in USD (\$)				500